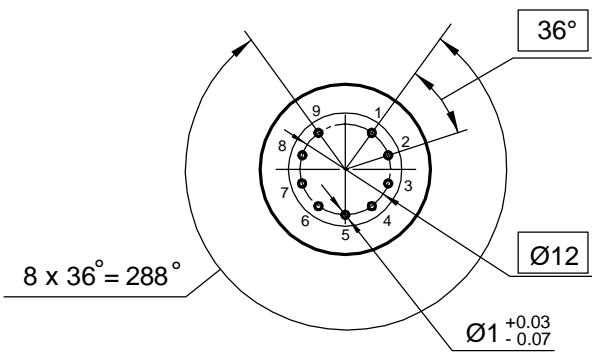
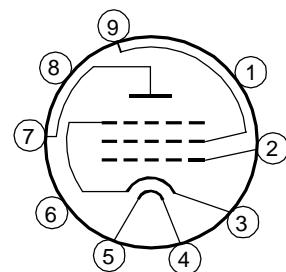


Vacuum tube EL84/6BQ5 is a miniature pentode with equipotential cathode, designed to amplify low frequency power in the output stages of HI-FI audio.

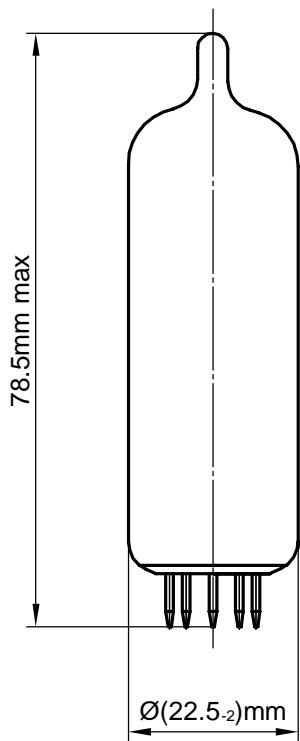
Pin arrangement



Electrode -to - lead connection diagram



Dimensions



Lead designation	Name of electrode
1, 6, 8	Free
2	Grid 1
3	Cathode, Grid 3
4, 5	Heater
7	Plate
9	Grid 2

Electrical parameters

EL84/6BQ5

Parameters, conditions and units	Nominal	
	min	max
First grid reverse current, μ A (at: filament voltage 6.3 V plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V, first grid circuit resistance 0.51M Ω)	—	1.0
Heater current, mA	700	840
Plate current, mA (at: filament voltage 6.3 V plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V)	30	60
Second grid current, mA (at: filament voltage 6.3 V plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V)	—	8.5
Output power, W (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V, plate circuit resistance 5.2 k Ω alternating first grid, efficacious 5.2 V)	3.0	—
Output power at low voltage, W (at: filament voltage 5.7 V plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V, plate circuit resistance 5.2 k Ω first grid alternating voltage, efficacious 5.2 V)	2.0	—
Slope of characteristic, mA/V (at: filament voltage 6.3 V plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V)	9.0	—
Distortion factor, % (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 7.3 V, second grid voltage 250 V, plate circuit resistance 5.2 k Ω alternating first grid, efficacious 5.2 V)	—	17
Cathode - heater insulation resistance, M Ω (at: filament voltage 6.3 V cathode -heater voltage \pm 100 V)	5.0	—

Limiting Values

Parameters, units	Nominal	
	min	max
Filament voltage, V	5.7	7.0
Plate voltage, V	—	300
Second grid voltage, V	—	300
Cathode - heater voltage, V	—	100
Cathode current, mA	—	65
Power dissipation at the plate, W	—	14
Power dissipation at the second grid, W	—	2.2
First grid circuit resistance, M Ω self - bias fixed bias	— — —	1.0 0.51
Temperature at the most heated part of the envelope, K°	—	493

EL84/6BQ5

